PSMN075-100MSE

N-channel 100 V 71 mΩ standard level MOSFET in LFPAK33 designed specifically for PoE applications

26 March 2013 Product data sheet

1. General description

New standards and proprietary approaches are enabling the next generation of Power-over-Ethernet (PoE) systems capable of delivering up to 100W to each powered device (PD). Large screen LCD displays, 3G / 4G / Wi-Fi hot-spots and pan-tilt-zoom CCTV cameras, for example, are placing increased demands on the power sourcing equipment (PSE) in terms of “soft-start” procedures, resilience to short-circuits, thermal management and power density. Part of Nexperia’s “NextPower Live” MOSFET portfolio, the PSMN075-100MSE has been designed specifically to compliment the latest PoE controllers, offering both superior linear mode operation and very low RDS(on) in a cost-effective, industry compatible, LFPAK33 package.

2. Features and benefits

- Enhanced forward biased safe operating area for superior linear mode operation
- Low Rdson for low conduction losses
- Ultra reliable LFPAK33 package – no glue, no wires, 175°C
- Very low I_{DSS}

3. Applications

- IEEE802.3at and proprietary solutions - (type 2)
- Suitable for PoE applications upto 30W
- Use PSMN040-100MSE for higher power requirements

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25$ °C; $T_j \leq 175$ °C		-	-	100	V
I_D	drain current	$T_j = 25$ °C; $V_{GS} = 10$ V; Fig. 1		-	-	18	A
P_{tot}	total power dissipation	$T_{mb} = 25$ °C; Fig. 2		-	-	65	W
Static characteristics							
R_{DSon}	drain-source on-state resistance	$V_{GS} = 10$ V; $I_D = 5$ A; $T_j = 25$ °C; Fig. 12		-	57	71	mΩ
Dynamic characteristics							
Q_{GD}	gate-drain charge	$V_{GS} = 10$ V; $I_D = 5$ A; $V_{DS} = 50$ V; T_j 25 °C; Fig. 14; Fig. 15		-	5.3	-	nC

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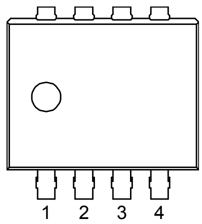
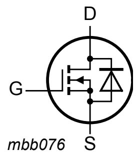
Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$Q_{G(tot)}$	total gate charge	V_{GS} = 10 V; I_D = 5 A; V_{DS} = 50 V; T_j = 25 °C; Fig. 14; Fig. 15		-	16.4	-	nC
Avalanche Ruggedness							
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_D = 18 A; V_{sup} ≤ 100 V; R_{GS} = 50 Ω; unclamped; Fig. 3		-	-	25	mJ

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	 LFPAK33 (SOT1210)	
2	S	source		
3	S	source		
4	G	gate		
mb	D	mounting base; connected to drain		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PSMN075-100MSE	LFPAK33	Plastic single ended surface mounted package (LFPAK33); 4 leads	SOT1210

7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN075-100MSE	M75E10

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DS}	drain-source voltage	T_j ≥ 25 °C; T_j ≤ 175 °C		-	100	V
V_{DGR}	drain-gate voltage	T_j ≥ 25 °C; T_j ≤ 175 °C; R_{GS} = 20 kΩ		-	100	V

Symbol	Parameter	Conditions		Min	Max	Unit
V_{GS}	gate-source voltage			-20	20	V
I_D	drain current	V_{GS} = 10 V; T_j = 25 °C; Fig. 1		-	18	A
		V_{GS} = 10 V; T_{mb} = 100 °C; Fig. 1		-	13	A
I_{DM}	peak drain current	pulsed; t_p ≤ 10 µs; T_{mb} = 25 °C; Fig. 4		-	74	A
P_{tot}	total power dissipation	T_{mb} = 25 °C; Fig. 2		-	65	W
T_{stg}	storage temperature			-55	175	°C
T_j	junction temperature			-55	175	°C
$T_{sld(M)}$	peak soldering temperature			-	260	°C
Source-drain diode						
I_S	source current	T_{mb} = 25 °C		-	54	A
I_{SM}	peak source current	pulsed; t_p ≤ 10 µs; T_{mb} = 25 °C		-	74	A
Avalanche Ruggedness						
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_D = 18 A; V_{sup} ≤ 100 V; R_{GS} = 50 Ω; unclamped; Fig. 3		-	25	mJ

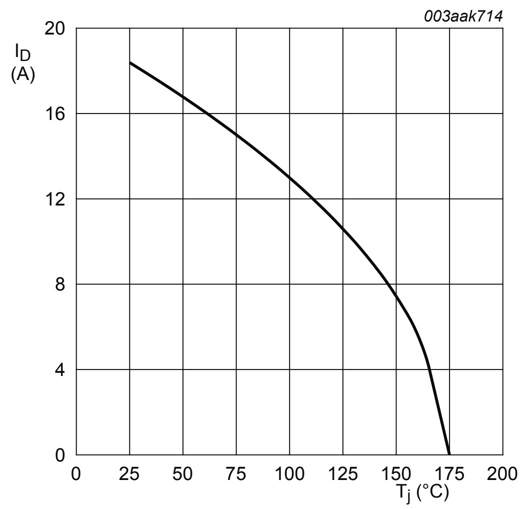


Fig. 1. Continuous drain current as a function of mounting base temperature

$$V_{GS} \geq 10V$$

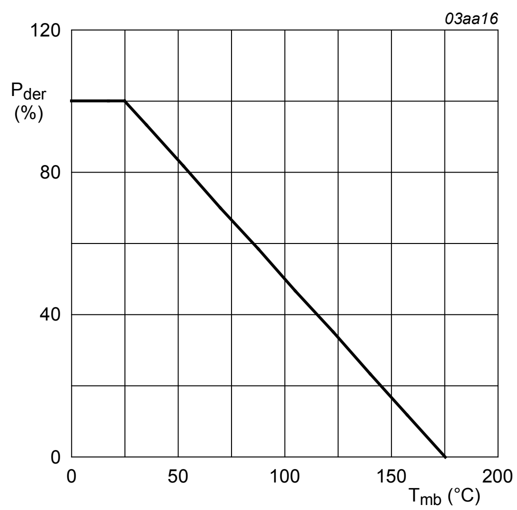


Fig. 2. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100\,\%$$

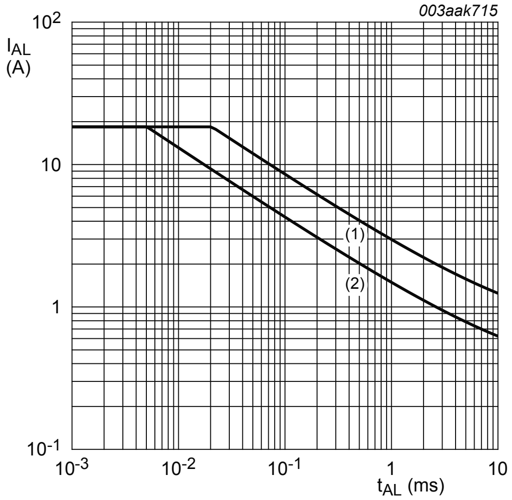


Fig. 3. Single pulse avalanche rating; avalanche current as a function of avalanche time

(1) $T_{j\ (init)} = 25°C$; (2) $T_{j\ (init)} = 100°C$

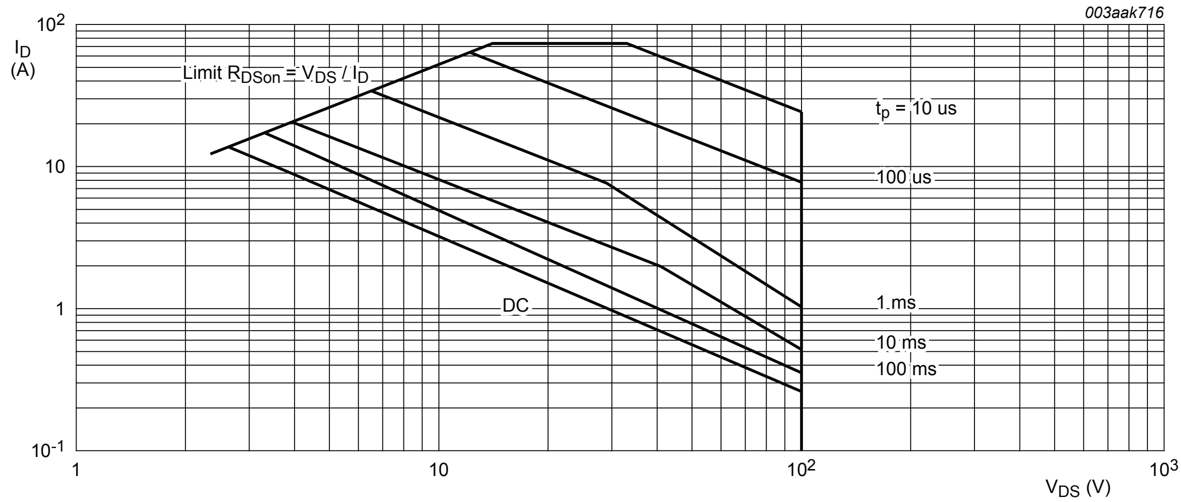


Fig. 4. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

$T_{mb} = 25°C$; I_{DM} is a single pulse

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j\text{-}mb)}$	thermal resistance from junction to mounting base	Fig. 5		-	2.09	2.32	K/W

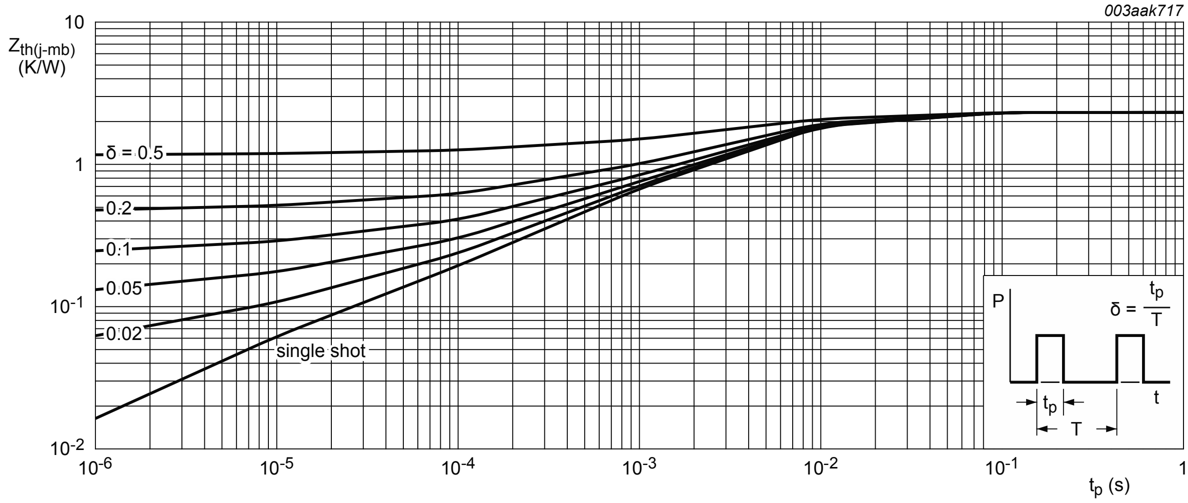


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Static characteristics							
$V_{(BR)DSS}$	drain-source breakdown voltage	I_D = 250 μA; V_{GS} = 0 V; T_j = 25 °C		100	-	-	V
		I_D = 250 μA; V_{GS} = 0 V; T_j = -55 °C		90	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	I_D = 1 mA; V_{DS} = V_{GS}; T_j = 25 °C; Fig. 10; Fig. 11		2.3	3.3	4	V
		I_D = 1 mA; V_{DS} = V_{GS}; T_j = 175 °C; Fig. 10		1	-	-	V
		I_D = 1 mA; V_{DS} = V_{GS}; T_j = -55 °C; Fig. 10		-	-	4.6	V
I_{DSS}	drain leakage current	V_{DS} = 100 V; V_{GS} = 0 V; T_j = 25 °C		-	0.01	1	μA
		V_{DS} = 100 V; V_{GS} = 0 V; T_j = 175 °C		-	-	500	μA
I_{GSS}	gate leakage current	V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25 °C		-	10	100	nA
		V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25 °C		-	10	100	nA
R_{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I_D = 5 A; T_j = 25 °C; Fig. 12		-	57	71	mΩ
		V_{GS} = 10 V; I_D = 5 A; T_j = 100 °C; Fig. 13; Fig. 12		-	-	128	mΩ
		V_{GS} = 10 V; I_D = 5 A; T_j = 175 °C; Fig. 13; Fig. 12		-	-	192	mΩ
R_G	gate resistance	f = 10 MHz		-	1.55	-	Ω

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Dynamic characteristics							
$Q_{G(tot)}$	total gate charge	I_D = 5 A; V_{DS} = 50 V; V_{GS} = 10 V; T_j = 25 °C; Fig. 14; Fig. 15		-	16.4	-	nC
		I_D = 0 A; V_{DS} = 0 V; V_{GS} = 10 V; T_j = 25 °C		-	12.9	-	nC
Q_{GS}	gate-source charge	I_D = 5 A; V_{DS} = 50 V; V_{GS} = 10 V; T_j = 25 °C; Fig. 14; Fig. 15		-	3.1	-	nC
$Q_{GS(th)}$	pre-threshold gate-source charge			-	2.1	-	nC
$Q_{GS(th-pl)}$	post-threshold gate-source charge			-	1	-	nC
Q_{GD}	gate-drain charge	I_D = 5 A; V_{DS} = 50 V; V_{GS} = 10 V; T_j 25 °C; Fig. 14; Fig. 15		-	5.3	-	nC
$V_{GS(pl)}$	gate-source plateau voltage	I_D = 5 A; V_{DS} = 50 V; T_j = 25 °C; Fig. 14; Fig. 15		-	4.3	-	V
C_{iss}	input capacitance	V_{DS} = 50 V; V_{GS} = 0 V; f = 1 MHz; T_j = 25 °C; Fig. 16		-	773	-	pF
C_{oss}	output capacitance			-	66	-	pF
C_{rss}	reverse transfer capacitance			-	48	-	pF
$t_{d(on)}$	turn-on delay time	V_{DS} = 50 V; R_L = 10 Ω; V_{GS} = 10 V; $R_{G(ext)}$ = 5 Ω; T_j = 25 °C		-	5.5	-	ns
t_r	rise time			-	5.8	-	ns
$t_{d(off)}$	turn-off delay time			-	12.4	-	ns
t_f	fall time			-	6.2	-	ns
Source-drain diode							
V_{SD}	source-drain voltage	I_S = 15 A; V_{GS} = 0 V; T_j = 25 °C; Fig. 17		-	0.89	1.2	V
t_{rr}	reverse recovery time	I_S = 5 A; dI_S/dt = -100 A/µs; V_{GS} = 0 V; V_{DS} = 50 V; T_j = 25 °C		-	35.8	-	ns
Q_r	recovered charge			-	50.7	-	nC

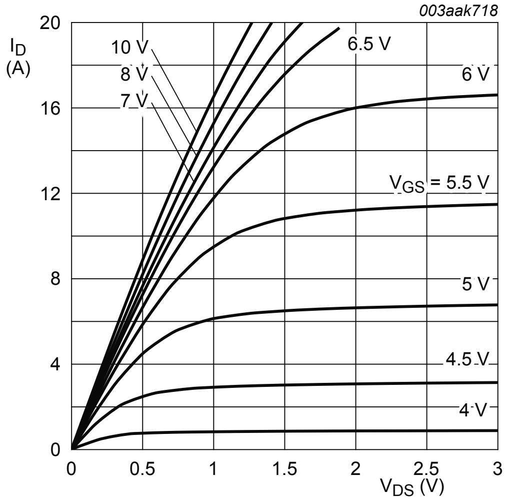


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values

$T_j = 25°C$

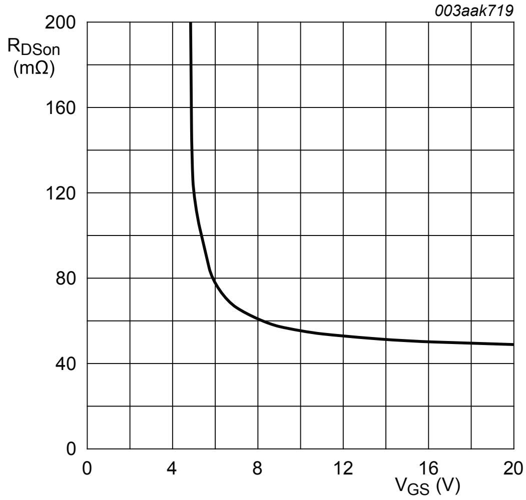


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

$T_j = 25°C; \ I_D = 5A$

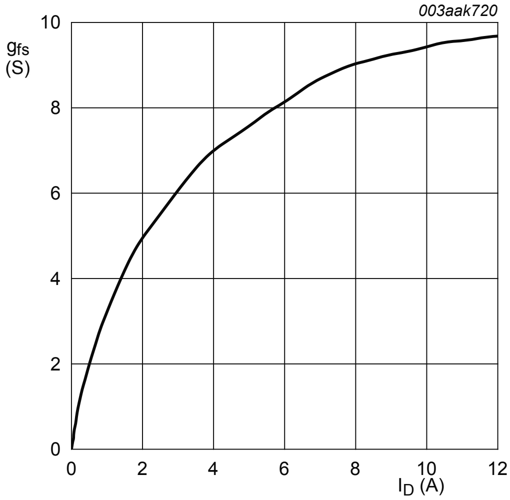


Fig. 8. Forward transconductance as a function of drain current; typical values

$T_j = 25°C; \ V_{DS} = 10V$

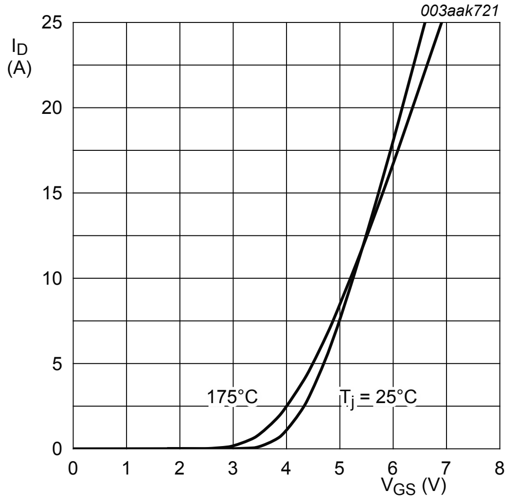


Fig. 9. Transfer characteristics; drain current as a function of gate-source voltage; typical values

$V_{DS} = 10V$

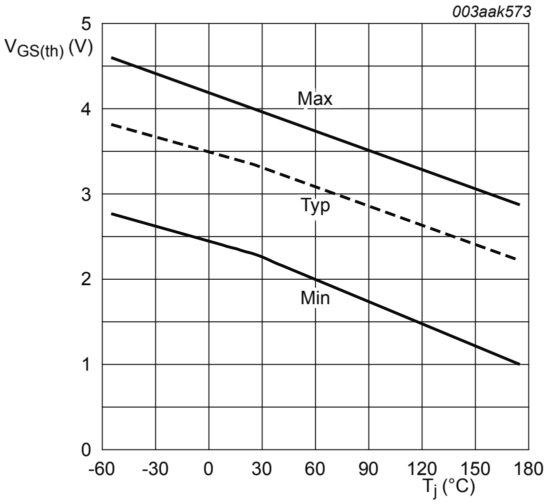


Fig. 10. Gate-source threshold voltage as a function of junction temperature

$I_D = 1$ mA; $V_{DS} = V_{GS}$

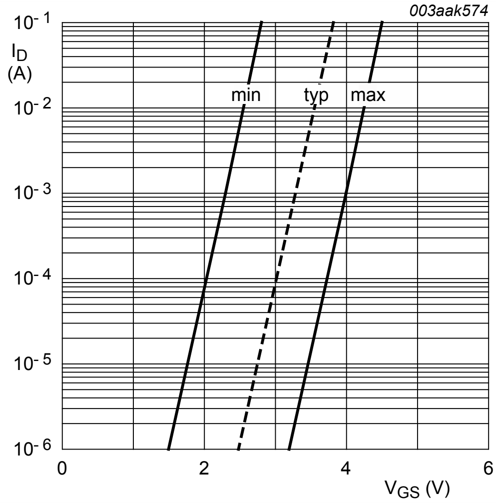


Fig. 11. Sub-threshold drain current as a function of gate-source voltage

$T_j = 25\,°C; V_{DS} = 5V$

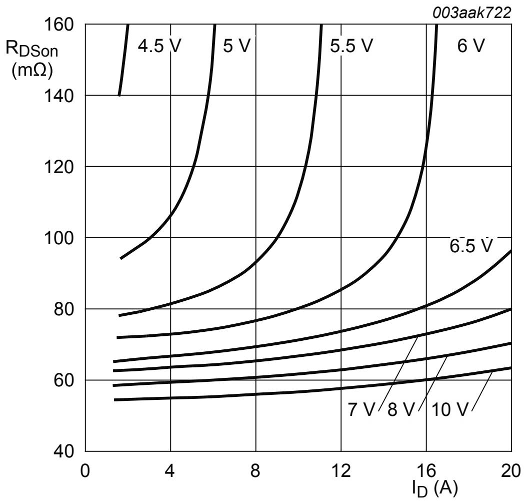


Fig. 12. Drain-source on-state resistance as a function of drain current; typical values

$T_j = 25°C$

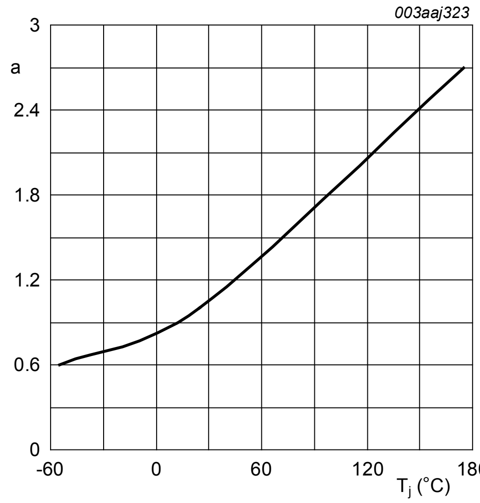


Fig. 13. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DSon}}{R_{DSon\,(25°C)}}$$

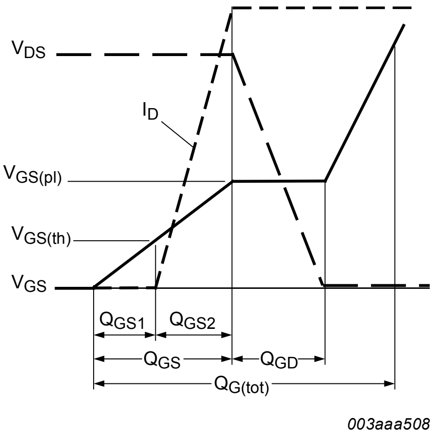


Fig. 14. Gate charge waveform definitions

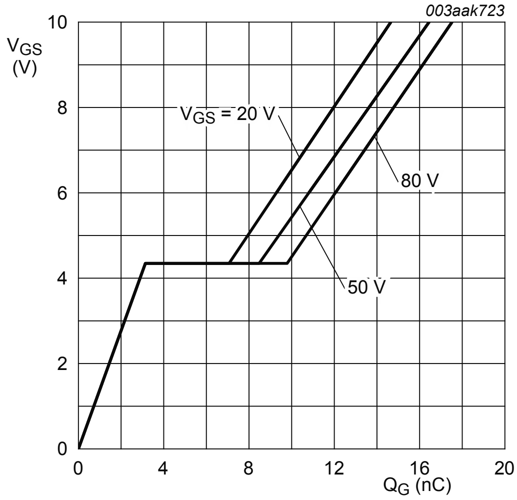


Fig. 15. Gate-source voltage as a function of gate charge; typical values

$T_j = 25°C;\ I_D = 5A$

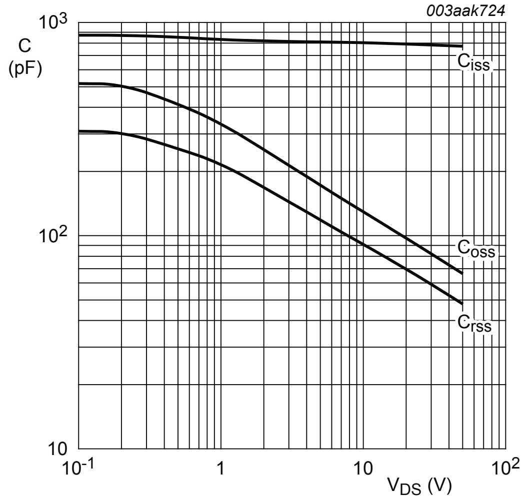


Fig. 16. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

$V_{GS} = 0V;\ f = 1MHz$

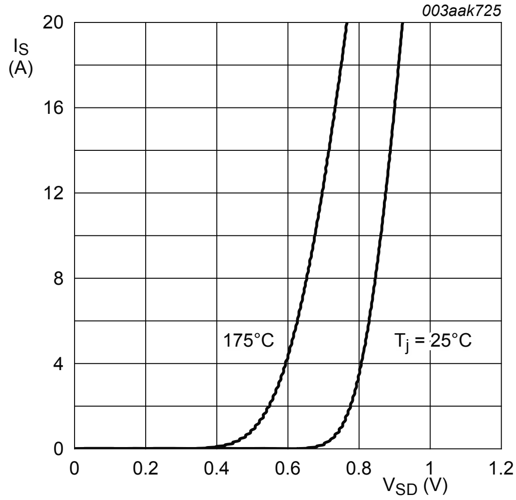
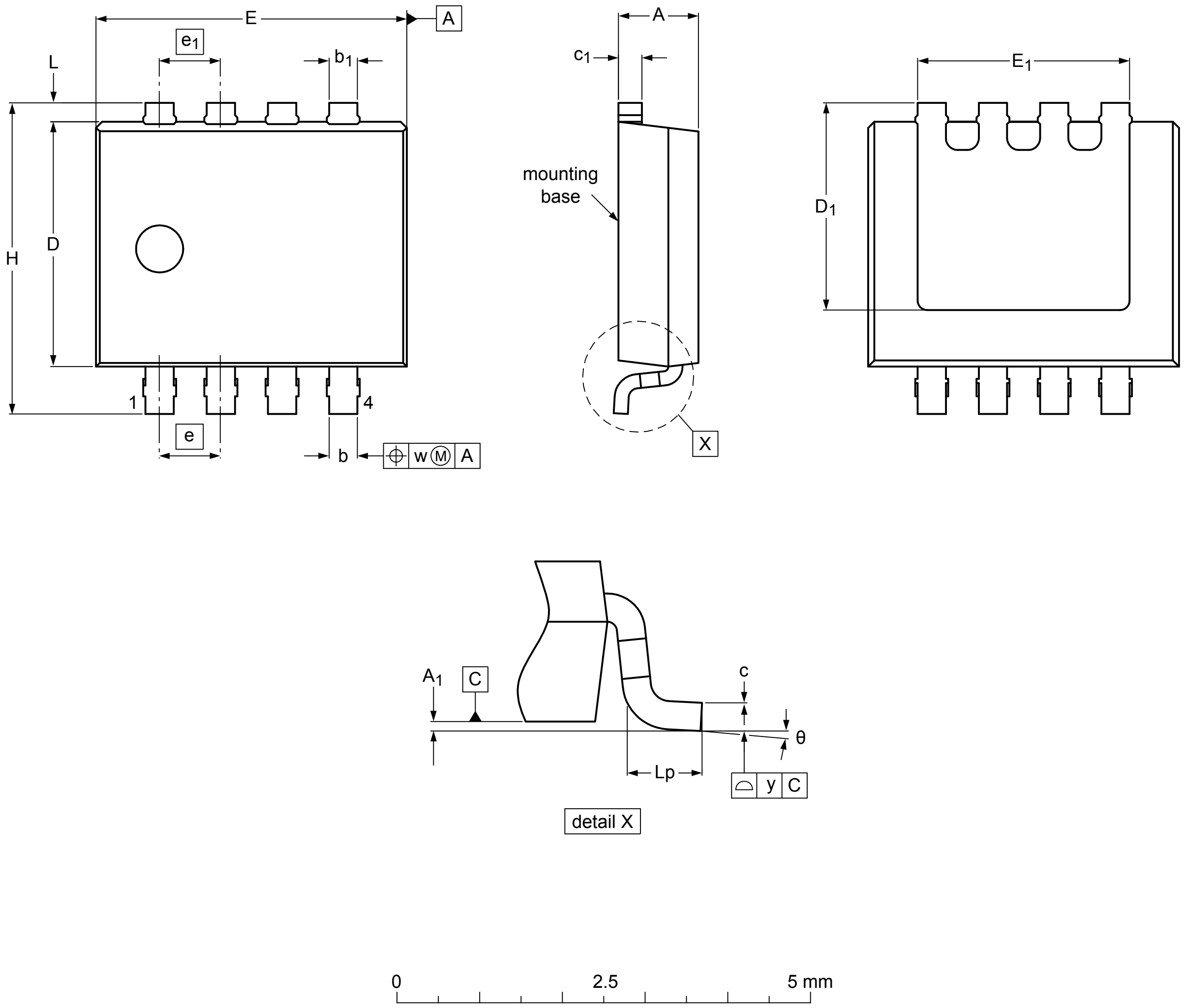


Fig. 17. Source current as a function of source-drain voltage; typical values

$V_{GS} = 0V$

11. Package outline

Plastic single ended surface mounted package (LFPAK33); 8 leads **SOT1210**



Dimensions

Unit(1)		A	A_1	b	b_1	c	c_1	D(1)	D_1	E(1)	E_1	e	e_1	H	L	L_p	w	y	θ
mm	max	0.90	0.10	0.35	0.35	0.20	0.30	2.70	2.35	3.40	2.45			3.40	0.25	0.50			8°
	nom											0.65	0.65				0.20	0.10	
	min	0.80	0.00	0.25	0.25	0.10	0.20	2.50	1.90	3.20	2.00			3.20	0.13	0.30			0°

Note

1. Plastic or metal protrusions of 0.15 mm per side are not included.

sot1210_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT1210						~~11-12-19~~ 12-03-12

Fig. 18. Package outline LFPAK33 (SOT1210)

12. Legal information

12.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.
[2] The term 'short data sheet' is explained in section "Definitions".
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13. Contents

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For sales office addresses, please send an email to: salesaddresses@nexperia.com
Date of release: 26 March 2013

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- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения **«JONHON»**, а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов **«FORSTAR»**.

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели, кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).

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